



MMUN5311DW Series

Dual Bias Resistor Transistors

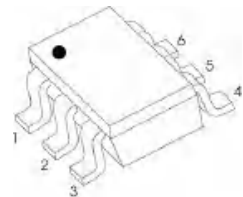
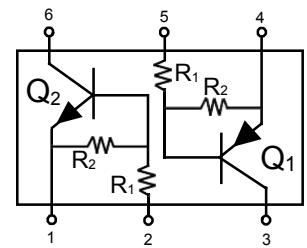
NPN and PNP Silicon Surface Mount

Transistors with Monolithic Bias

Resistor Network

The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. These digital transistors are designed to replace a single device and its external resistor bias network. The BRT eliminates these individual components by integrating them into a single device. In the MMUN5311DWseries, two complementary BRT devices are housed in the SOT-363 package which is ideal for low power surface mount applications where board space is at a premium.

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- We declare that the material of product compliance with RoHS requirements.



SOT-363

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted, common for Q₁

and Q₂, – minus sign for Q₁ (PNP) omitted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	Vdc
Collector-Emitter Voltage	V _{CEO}	50	Vdc
Collector Current	I _C	100	mAdc

THERMAL CHARACTERISTICS

Characteristic (One Junction Heated)	Symbol	Max	Unit
Total Device Dissipation T _A = 25°C	P _D	187 (Note 1.) 256 (Note 2.)	mW
Derate above 25°C		1.5 (Note 1.) 2.0 (Note 2.)	mW/°C
Thermal Resistance – Junction-to-Ambient	R _{θJA}	670 (Note 1.) 490 (Note 2.)	°C/W
Characteristic (Both Junctions Heated)	Symbol	Max	Unit
Total Device Dissipation T _A = 25°C	P _D	250 (Note 1.) 385 (Note 2.)	mW
Derate above 25°C		2.0 (Note 1.) 3.0 (Note 2.)	mW/°C
Thermal Resistance – Junction-to-Ambient	R _{θJA}	493 (Note 1.) 325 (Note 2.)	°C/W
Thermal Resistance – Junction-to-Lead	R _{θJL}	188 (Note 1.) 208 (Note 2.)	°C/W
Junction and Storage Temperature	T _J , T _{stg}	–55 to +150	°C



ORDERING, SHIPPING, DEVICE MARKING AND RESISTOR VALUES

Device	Package	Marking	R1(K)	R2(K)	Shipping
MMUN5311DW	SOT-363	11	10	10	3000/Tape&Reel
MMUN5312DW	SOT-363	12	22	22	3000/Tape&Reel
MMUN5313DW	SOT-363	13	47	47	3000/Tape&Reel
MMUN5314DW	SOT-363	14	10	47	3000/Tape&Reel
MMUN5315DW	SOT-363	15	10	Ġ	3000/Tape&Reel
MMUN5316DW	SOT-363	16	4.7	Ġ	3000/Tape&Reel
MMUN5330DW	SOT-363	30	1	1	3000/Tape&Reel
MMUN5331DW	SOT-363	31	2.2	2.2	3000/Tape&Reel
MMUN5332DW	SOT-363	32	4.7	4.7	3000/Tape&Reel
MMUN5333DW	SOT-363	33	4.7	47	3000/Tape&Reel
MMUN5334DW	SOT-363	34	22	47	3000/Tape&Reel
MMUN5335DW	SOT-363	35	2.2	47	3000/Tape&Reel



ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted, common for Q₁ and Q₂, – minus sign for Q₁ (PNP) omitted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
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ON CHARACTERISTICS (Note 4)

DC Current Gain (V _{CE} = 10 V, I _C = 5.0 mA)	MMUN5311DW MMUN5312DW MMUN5313DW MMUN5314DW MMUN5315DW MMUN5316DW MMUN5330DW MMUN5331DW MMUN5332DW MMUN5333DW MMUN5334DW MMUN5335DW	h _{FE}	35 60 80 80 160 160 3.0 8.0 15 80 80 80	60 100 140 140 350 350 5.0 15 30 200 150 140	– – – – – – – – – – – –	
Collector-Emitter Saturation Voltage (I _C = 10 mA, I _B = 0.3 mA) (I _C = 10 mA, I _B = 5 mA) MMUN5330DW /MMUN5331DW (I _C = 10 mA, I _B = 1 mA) LMUN5315DW/MMUN5316DW MMUN5332DW /MMUN5333DW /MMUN5334DW		V _{CE(sat)}	–	–	0.25	V _{dc}
Output Voltage (on) (V _{CC} = 5.0 V, V _B = 2.5 V, R _L = 1.0 kfi) (V _{CC} = 5.0 V, V _B = 3.5 V, R _L = 1.0 kfi)	MMUN5311DW MMUN5312DW MMUN5314DW MMUN5315DW MMUN5316DW MMUN5330DW MMUN5331DW MMUN5332DW MMUN5333DW MMUN5334DW MMUN5335DW MMUN5313DW	V _{OL}	– – – – – – – – – – – –	– – – – – – – – – – – –	0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2	V _{dc}
Output Voltage (off) (V _{CC} = 5.0 V, V _B = 0.5 V, R _L = 1.0 kfi) (V _{CC} = 5.0 V, V _B = 0.050 V, R _L = 1.0 kfi) (V _{CC} = 5.0 V, V _B = 0.25 V, R _L = 1.0 kfi)	MMUN5330DW MMUN5315DW MMUN5316DW MMUN5333DW	V _{OH}	4.9	–	–	V _{dc}
Input Resistor	MMUN5311DW MMUN5312DW MMUN5313DW MMUN5314DW MMUN5315DW MMUN5316DW MMUN5330DW MMUN5331DW MMUN5332DW MMUN5333DW MMUN5334DW MMUN5335DW	R ₁	7.0 15.4 32.9 7.0 7.0 3.3 0.7 1.5 3.3 3.3 15.4 1.54	10 22 47 10 10 4.7 1.0 2.2 4.7 4.7 22 2.2	13 28.6 61.1 13 13 6.1 1.3 2.9 6.1 6.1 28.6 2.86	k fi
Resistor Ratio	MMUN5311DW /MMUN5312DW MMUN5313DW /MMUN5314DW MMUN5315DW /MMUN5316DW MMUN5330DW /MMUN5331DW MMUN5332DW /MMUN5333DW MMUN5334DW /MMUN5335DW	R ₁ /R ₂	0.8 0.17 – 0.8 0.055 0.38 0.038	1.0 0.21 – 1.0 0.1 0.47 0.047	1.2 0.25 – 1.2 0.185 0.56 0.056	



ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise noted, common for Q_1 and Q_2 , - minus sign for Q_1 (PNP) omitted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector-Base Cutoff Current ($V_{CB} = 50\text{ V}$, $I_E = 0$)	I_{CBO}	-	-	100	nAdc
Collector-Emitter Cutoff Current ($V_{CE} = 50\text{ V}$, $I_B = 0$)	I_{CEO}	-	-	500	nAdc
Emitter-Base Cutoff Current ($V_{EB} = 6.0\text{ V}$, $I_C = 0$)	MMUN5311DW	-	-	0.5	mAdc
	MMUN5312DW	-	-	0.2	
	MMUN5313DW	-	-	0.1	
	MMUN5314DW	-	-	0.2	
	MMUN5315DW	-	-	0.9	
	MMUN5316DW	-	-	1.9	
	MMUN5330DW	-	-	4.3	
	MMUN5331DW	-	-	2.3	
	MMUN5332DW	-	-	1.5	
	MMUN5333DW	-	-	0.18	
	MMUN5334DW	-	-	0.13	
	MMUN5335DW	-	-	0.2	
Collector-Base Breakdown Voltage ($I_C = 10\text{ }\mu\text{A}$, $I_E = 0$)	$V_{(BR)CBO}$	50	-	-	Vdc
Collector-Emitter Breakdown Voltage (Note 3) ($I_C = 2.0\text{ mA}$, $I_B = 0$)	$V_{(BR)CEO}$	50	-	-	Vdc

3. Pulse Test: Pulse Width < 300 μs , Duty Cycle < 2.0%

ALL MMUN5311DW1T1G SERIES DEVICES

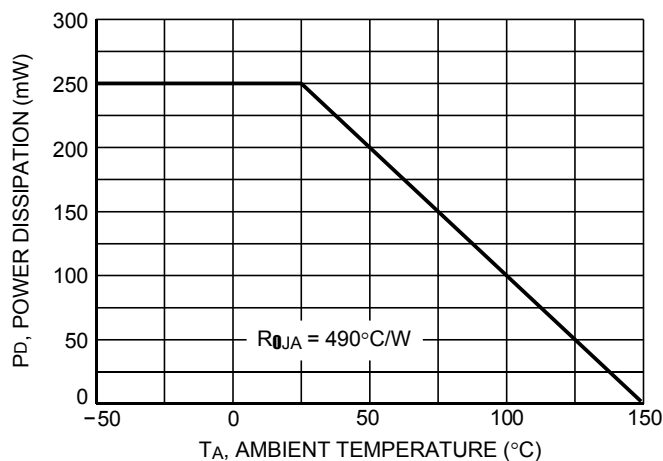


Figure 1. Derating Curve



TYPICAL ELECTRICAL CHARACTERISTICS – MMUN5311DW NPN TRANSISTOR

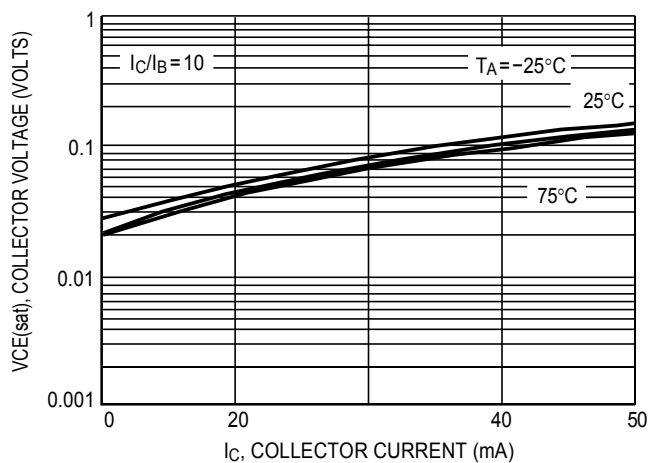


Figure 2. $V_{CE(sat)}$ versus I_C

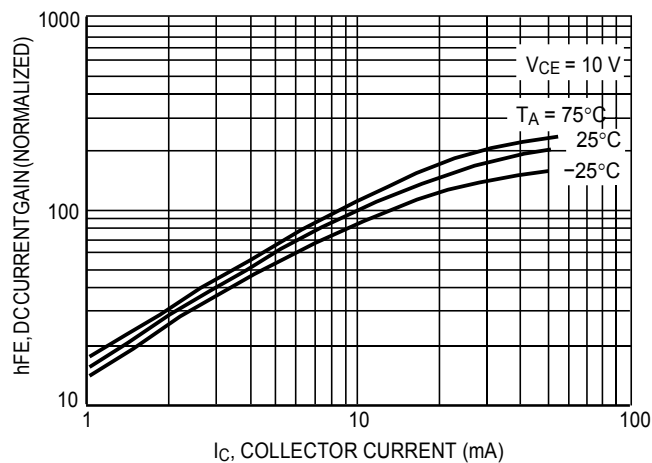


Figure 3. DC Current Gain

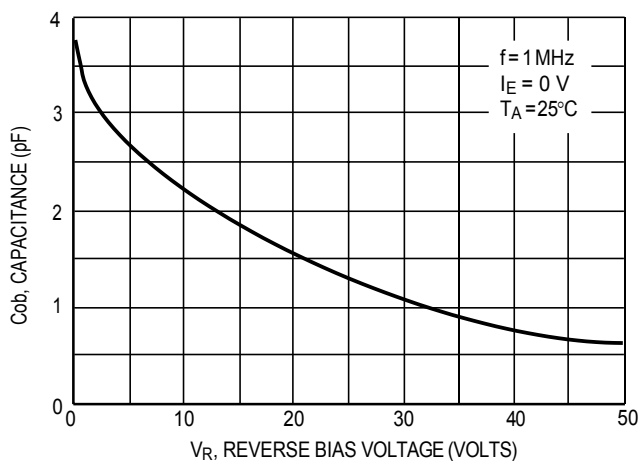


Figure 4. Output Capacitance

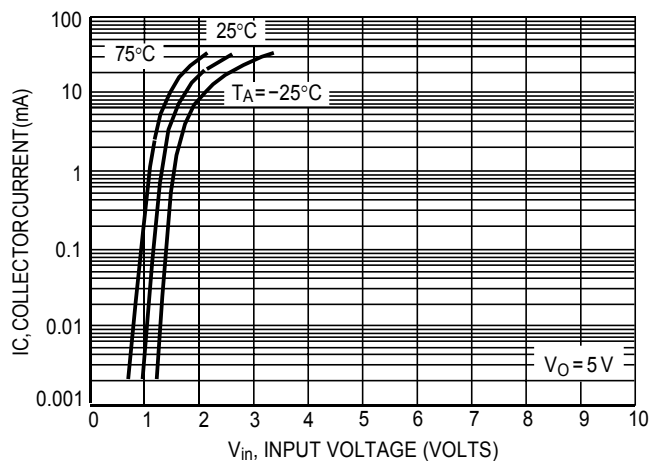


Figure 5. Output Current versus Input Voltage

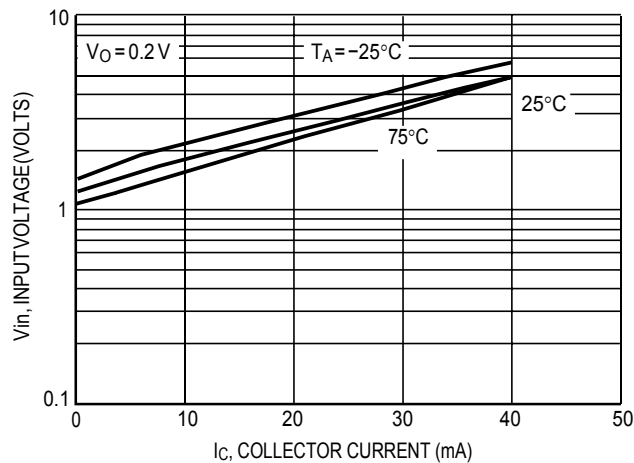


Figure 6. Input Voltage versus Output Current



TYPICAL ELECTRICAL CHARACTERISTICS – MMUN5311DW PNP TRANSISTOR

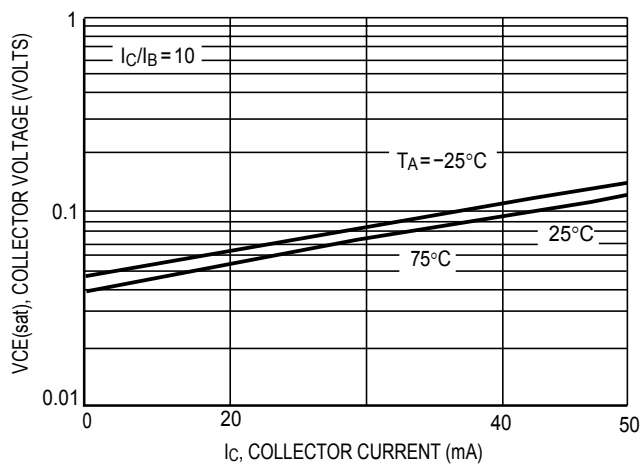


Figure 7. $V_{CE(sat)}$ versus I_C

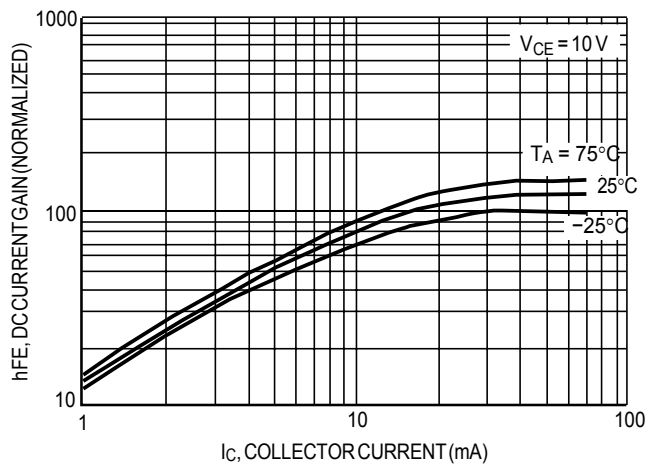


Figure 8. DC Current Gain

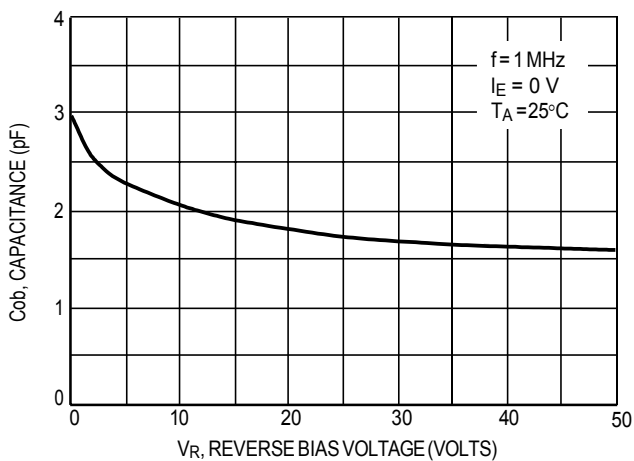


Figure 9. Output Capacitance

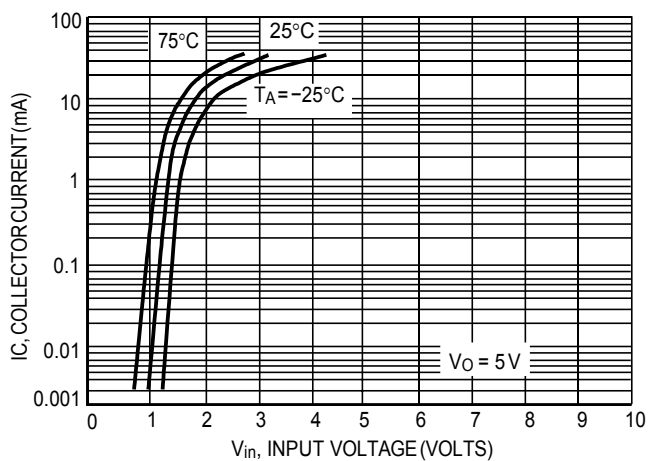


Figure 10. Output Current versus Input Voltage

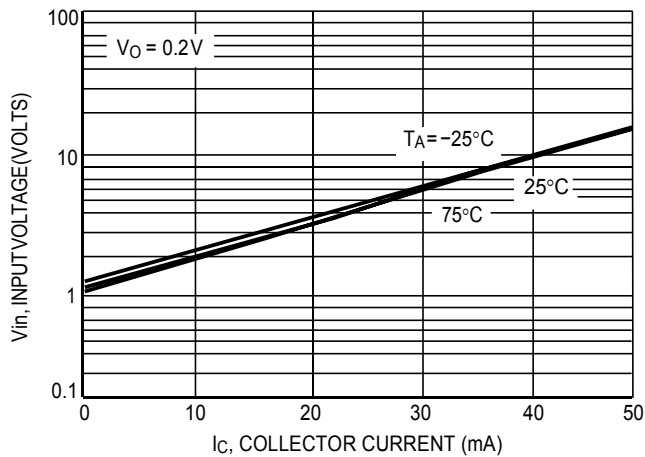
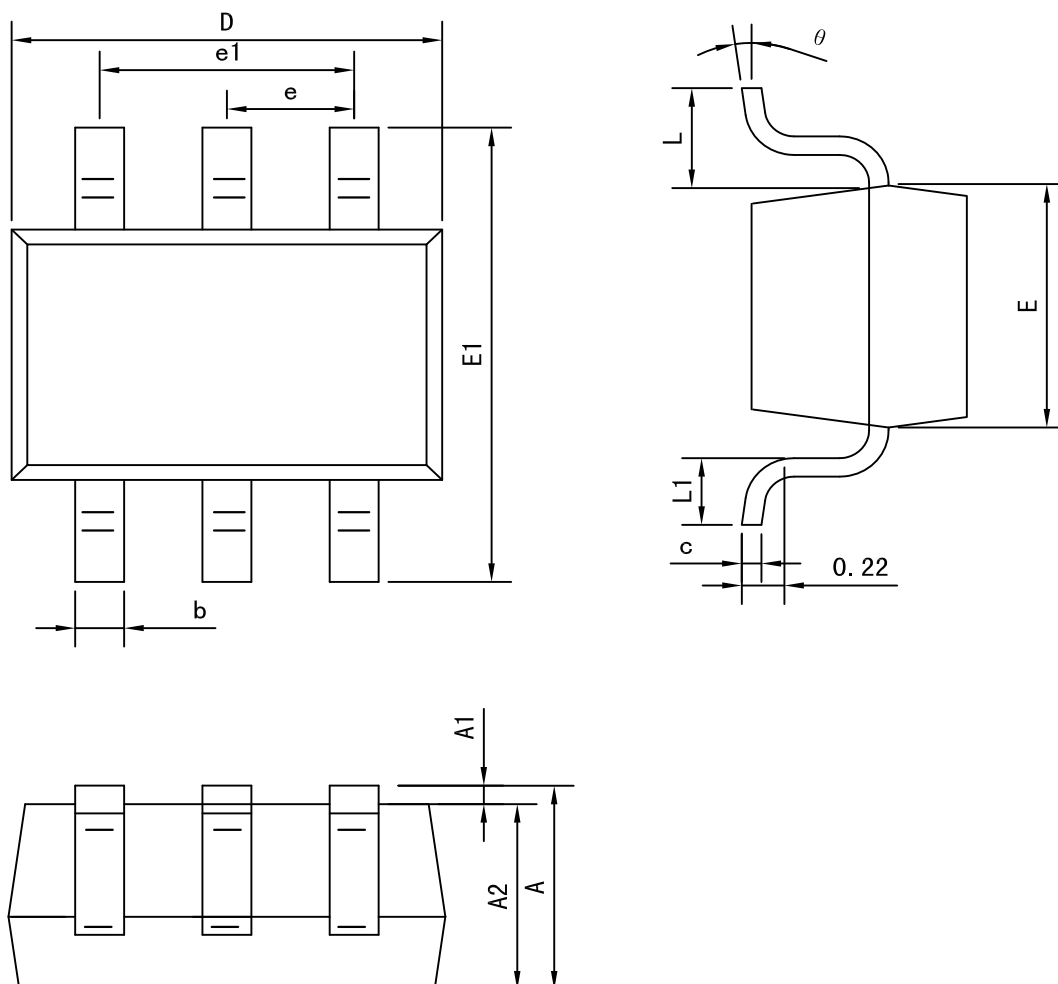


Figure 11. Input Voltage versus Output Current



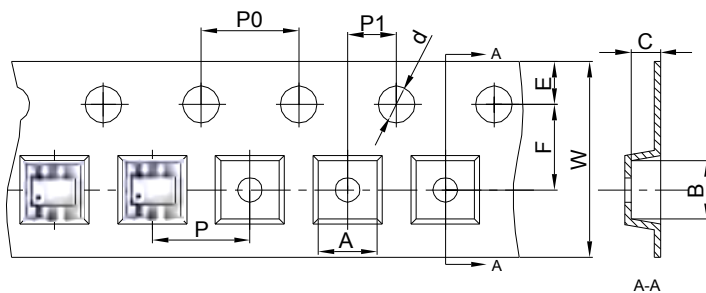
SOT-363 Package outline dimensions



Symbol	Dimension in Millimeters	
	Min	Max
A	0.900	1.100
A1	0.000	0.100
A2	0.900	1.000
b	0.150	0.350
c	0.080	0.150
D	2.000	2.200
E	1.150	1.350
E1	2.150	2.450
e	0.650 TYP	
e1	1.200	1.400
L	0.525 REF	
L1	0.260	0.460
θ	0°	8°



SOT-363 Embossed Carrier Tape



Packaging Description:

SOT-363 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-363	2.25	2.55	1.20	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-363 Tape Leader and Trailer "Forward"

